

Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature	–65°C to +150°C
Ambient Temperature with Power Applied	–40°C to +85°C
Supply Voltage to Ground Potential (Inputs & V _{CC} Only)	–0.5V to +7.0V
Supply Voltage to Ground Potential (Outputs & D/O Only) ..	–0.5V to +7.0V
DC Input Voltage	–0.5V to +7.0V
DC Output Current	120 mA
Power Dissipation	0.5W

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

DC Electrical Characteristics (Over the Operating Range, T_A = –40°C to +85°C, V_{CC} = 5.0V ± 5%)

Parameters	Description	Test Conditions ⁽¹⁾		Min.	Typ ⁽²⁾	Max.	Units
V _{OH}	Output HIGH Voltage	V _{CC} = Min., V _{IN} = V _{IH} or V _{IL}	I _{OH} = –15.0mA	2.4	3.0		V
V _{OL}	Output LOW Current	V _{CC} = Min., V _{IN} = V _{IH} or V _{IL}	I _{OL} = 64mA		0.3	0.55	V
V _{OL}	Output LOW Current	V _{CC} = Min., V _{IN} = V _{IH} or V _{IL}	I _{OL} = 12mA		0.3	0.50	V
V _{IH}	Input HIGH Voltage	Guaranteed Logic HIGH Level		2.0			V
V _{IL}	Input LOW Voltage	Guaranteed Logic LOW Level				0.8	V
I _{IH}	Input HIGH Current	V _{CC} = Max.	V _{IN} = V _{CC}			1	μA
I _{IL}	Input LOW Current	V _{CC} = Max.	V _{IN} = GND			–1	μA
I _{OZH}	High Impedance	V _{CC} = Max.	V _{OUT} = 2.7V			1	μA
I _{OZL}	Output Current		V _{OUT} = 0.5V			–1	μA
V _{IK}	Clamp Diode Voltage	V _{CC} = Min., I _{IN} = –18mA			–0.7	–1.2	V
I _{OFF}	Power Down Disable	V _{CC} = GND, V _{OUT} = 4.5V				100	μA
I _{OS}	Short Circuit Current	V _{CC} = Max. ⁽³⁾ , V _{OUT} = GND		–60	–120		mA
V _H	Input Hysteresis				200		mV

Notes:

- For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
- Typical values are at V_{CC} = 5.0V, +25°C ambient and maximum loading.
- Not more than one output should be shorted at one time. Duration of the test should not exceed one second.

Capacitance (T_A = 25°C, f = 1 MHz)

Parameters ⁽¹⁾	Description	Test Conditions	Typ	Max.	Units
C _{IN}	Input Capacitance	V _{IN} = 0V	6	10	pF
C _{OUT}	Output Capacitance	V _{OUT} = 0V	8	12	pF

Notes:

- This parameter is determined by device characterization but is not production tested.

Power Supply Characteristics

Parameters	Description	Test Conditions ⁽¹⁾		Min.	Typ ⁽²⁾	Max.	Units
I _{CC}	Quiescent Power Supply Current	V _{CC} = Max.	V _{IN} = GND or V _{CC}		0.1	500	μA
ΔI _{CC}	Supply Current per per Input @ TTL HIGH	V _{CC} = Max.	V _{IN} = 3.4V ⁽³⁾		0.5	2.0	mA
I _{CCD}	Supply Current per Input per MHz ⁽⁴⁾	V _{CC} = Max., Outputs Open MR = V _{CC} , One Input Toggling 50% Duty Cycle	V _{IN} = V _{CC} V _{IN} = GND		0.15	0.25	mA/ MHz
I _C	Total Power Supply Current ⁽⁶⁾	V _{CC} = Max., Outputs Open f _{CP} = 10 MHz, 50% Duty Cycle MR = V _{CC} , 50% Duty Cycle One Bit toggling at f _i = 5 MHz	V _{IN} = V _{CC} V _{IN} = GND		1.5	3.5 ⁽⁵⁾	mA
			V _{IN} = 3.4V V _{IN} = GND		2.0	3.5 ⁽⁵⁾	
		V _{CC} = Max., Outputs Open f _{CP} = 10 MHz, 50% Duty Cycle MR = V _{CC} , 50% Duty Cycle Eight Bits toggling at f _i = 2.5 MHz, 50% Duty Cycle	V _{IN} = V _{CC} V _{IN} = GND		3.8	7.3 ⁽⁵⁾	
			V _{IN} = 3.4V V _{IN} = GND		6.0	16.3 ⁽⁵⁾	

Notes:

- For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device.
- Typical values are at V_{CC} = 5.0V, +25°C ambient.
- Per TTL driven input (V_{IN} = 3.4V); all other inputs at V_{CC} or GND.
- This parameter is not directly testable, but is derived for use in Total Power Supply Calculations.
- Values for these conditions are examples of the I_{CC} formula. These limits are guaranteed but not tested.
- I_C = I_{QUIESCENT} + I_{INPUTS} + I_{DYNAMIC}
 $I_C = I_{CC} + \Delta I_{CC} D_H N_T + I_{CCD} (f_{CP}/2 + f_i N_i)$
I_{CC} = Quiescent Current
ΔI_{CC} = Power Supply Current for a TTL High Input (V_{IN} = 3.4V)
D_H = Duty Cycle for TTL Inputs High
N_T = Number of TTL Inputs at D_H
I_{CCD} = Dynamic Current Caused by an Input Transition Pair (HLH or LHL)
f_{CP} = Clock Frequency for Register Devices (Zero for Non-Register Devices)
f_i = Input Frequency
N_i = Number of Inputs at f_i
All currents are in milliamps and all frequencies are in megahertz.

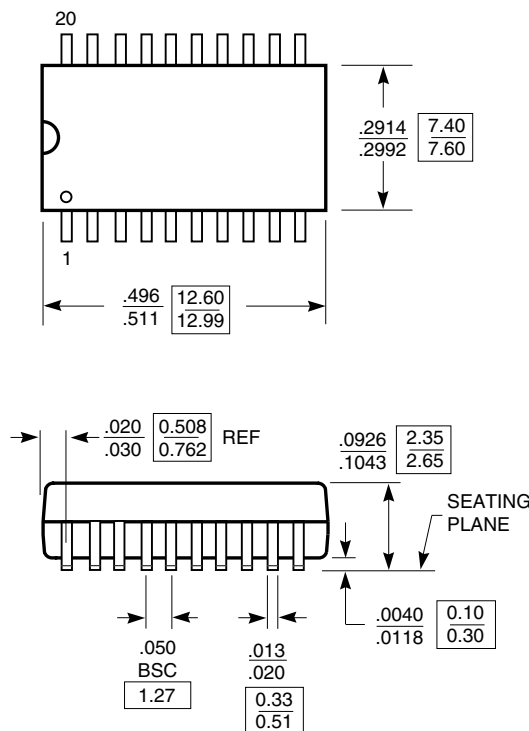
Switching Characteristics over Operating Range

Parameters	Description	Conditions	273T		273AT		273CT		Unit
			Com.		Com.		Com.		
			Min	Max	Min	Max	Min	Max	
tPLH	PropagationDelay ⁽¹⁾ CP to ON	CL= 50pF RL= 500Ω	2.0	13.0	2.0	7.2	2.0	5.8	ns
tPHL	PropagationDelay ⁽¹⁾ MR to ON		2.0	13.0	2.0	7.2	2.0	6.1	ns
tSU	Setup Time, HIGHorLOW Dn to CP		3.0		2.0		2.0		ns
tH	HoldTime, HIGHorLOW Dn to CP		2.0		1.5		1.5		ns
tw	CP Pulse Width ⁽²⁾ HIGHorLOW		7.0		6.0		6.0		ns
tw	MR Pulse Width ⁽²⁾ LOW		7.0		6.0		6.0		ns
tREM	Recovery Time MR to CP ⁽²⁾		4.0		2.0		2.0		ns

Notes:

1. Minimum limits are guaranteed but not tested on Propagation Delays.
2. This parameter guaranteed but not production tested.

Packaging Mechanical: 20-pin SOIC (S)



X.XX DENOTES CONTROLLING
X.XX DIMENSIONS IN MILLIMETERS

Notes:

- 1) Controlling dimensions in millimeters.
- 2) Ref: JEDEC MS-013D/AC

DOCUMENT CONTROL NO.
PD - 1006

REVISION: D
DATE: 03/09/05



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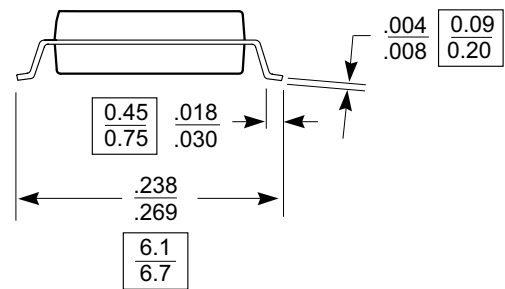
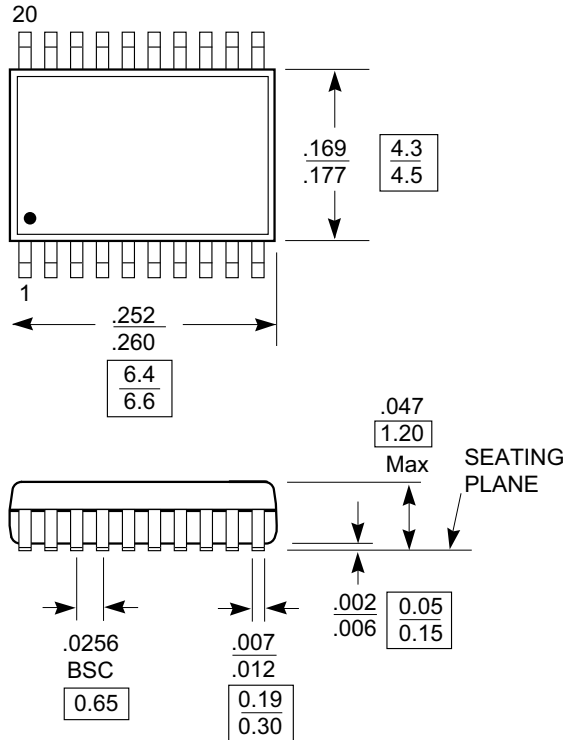
DESCRIPTION: 20-Pin, 300-Mil Wide, SOIC

PACKAGE CODE: S

Packaging Mechanical: 20-Pin TSSOP (L)

DOCUMENT CONTROL NO.
PD - 1311

REVISION: E
DATE: 03/09/05



Note:

- Package Outline Exclusive of Mold Flash and Metal Burr
- Controlling dimensions in millimeters
- Ref: JEDEC MO-153F/AC



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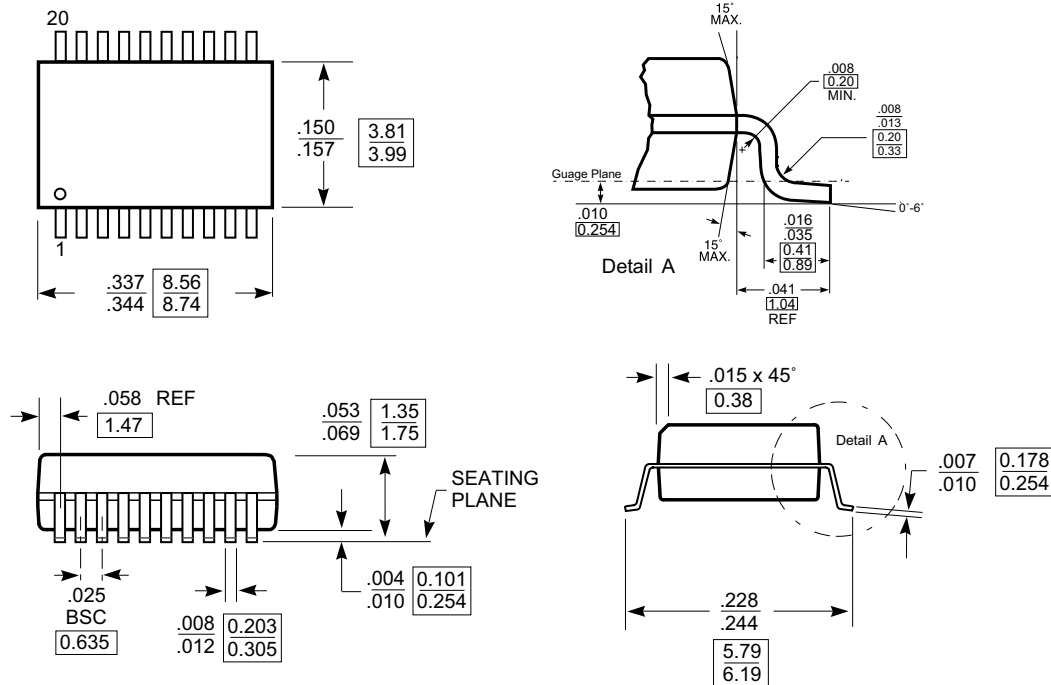
DESCRIPTION: 20-Pin, 173-Mil Wide, TSSOP

PACKAGE CODE: L

Packaging Mechanical: 20-pin QSOP (Q)

DOCUMENT CONTROL NO.
PD - 1202

REVISION: H
DATE: 10/22/07



X.XX DENOTES DIMENSIONS
X.XX IN MILLIMETERS

Note:
1) Controlling dimensions in inches.
2) Ref: JEDEC MO-137B/AD
3) Dimensions do not include mold flash, protrusions or gate burrs



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DESCRIPTION: 20-Pin, 150-Mil Wide, QSOP

PACKAGE CODE: Q

Ordering Information

Ordering Code	Package Code	Speed Grade	Package Type
PI74FCT273TQ	Q	Blank	20-pin QSOP
PI74FCT273TSE	S	Blank	Pb-free & Green, 20-pin SOIC
PI74FCT273ATL	L	A	20-pin TSSOP
PI74FCT273ATS	S	A	20-pin SOIC
PI74FCT273ATSE	S	A	Pb-free & Green, 20-pin SOIC
PI74FCT273ATQ	Q	A	20-pin QSOP

Notes:

- Thermal characteristics can be found on the company web site at www.pericom.com/packaging/
- E = Pb-free & Green
- Adding an X suffix = Tape/Reel

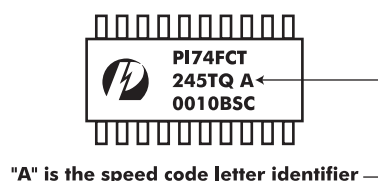
Part Marking Information

Pericom's standard product mark follows our standard part number ordering information, except for those products with a speed letter code. For marking purposes, the speed letter code mark is placed after the package code letter, rather than after the device number as it is ordered.

Although all products are marked immediately after assembly to assure material traceability, Pericom does not usually mark the speed code at that time. After electrical test screening and speed binning have been completed, we then perform an "add mark" operation which places the speed code letter at the end of the complete part number.

Please refer to the example shown below:

- Part Number as ordered: PI74FCT245ATQ
- Example of Part Number as marked:



Notes:

- 8-pin DIP, 8-pin SOIC, 8-pin TSSOP, 14-pin SOIC, 16-pin QSOP, SC70, MSOP, and SOT23 packages are not marked with the Pericom logo due to space limitations on the package.